

Features

- Lead free
- RoHS compliant*
- Reverse voltage from 20 to 60 V
- Forward current of 1 A
- High current capability

 For use in low voltage high frequency inverters, free wheeling and polarity protection applications

CD214B-B120 ~ B160 Schottky Barrier Rectifier Chip Diode

General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components.

Bourns offers Schottky Rectifier Diodes for rectification applications, in compact chip package DO-214AA (SMB) size format, which offer PCB real estate savings and are considerably smaller than most competitive parts. The Schottky Rectifier Diodes offer a forward current of 1 A with a choice of repetitive peak reverse voltage of 20 V up to 60 V.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle with standard pick and place equipment and the flat configuration minimizes roll away.

Electrical Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	CD214B-						I I i A
	Symbol	B120	B130	B140	B150	B160	Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	30	40	50	60	V
Maximum RMS Voltage	V _{RMS}	14	21	28	35	42	V
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	60	V
Maximum Average Forward Rectified Current ¹	I _(AV)	1				А	
DC Reverse Current @ Rated DC Blocking Voltage (@T _A = 25 °C)	IR	0.5			mA		
DC Reverse Current @ Rated DC Blocking Voltage (@T _A = 100 °C)	I _R	10			mA		
Typical Junction Capacitance ²	CJ	110			pF		
Maximum Instantaneous Forward Voltage @ 1 A	V _F	0.5 0.7			.7	V	
Typical Thermal Resistance ³	$R_{\theta JA}$	22			°C/W		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30			А		

Notes:

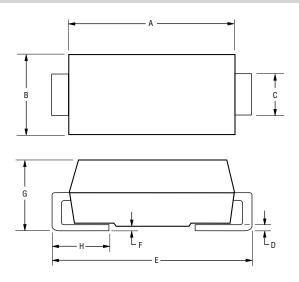
- 1 See Forward Derating Curve.
- 2 Measured at 1 MHz and an applied reverse voltage of 4.0 V.
- 3 Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2 x 0.2 " (5.0 x 5.0 mm) copper pad areas.

Thermal Characteristics (@ T_A = 25 °C Unless Otherwise Noted)

Parameter	Symbol	CD214B-					Unit
	Symbol	B120	B130	B140	B150	B160	
Operating Temperature Range	TJ	-55 to +125		-55 to +125 -55 to +150		+150	°C
Storage Temperature Range	TSTG	-55 to +150		°C			

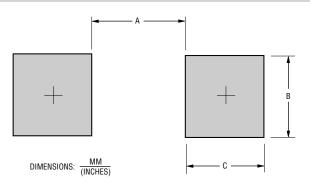
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Product Dimensions



Dimension	SMB (DO-214AA)		
А	4.06 - 4.57		
	(0.160 - 0.180)		
В	3.30 - 3.94		
	(0.130 - 0.155)		
С	1.96 - 2.21		
	(0.078 - 0.087)		
D	0.15 - 0.31		
	(0.006 - 0.112)		
E	5.21 - 5.59		
	(0.205 - 0.220)		
F	0.05 - 0.20		
	(0.002 - 0.008)		
G	2.01 - 2.62		
	(0.080 - 0.103)		
Н	0.76 - 1.52		
	(0.030 - 0.060)		
	(0.030 - 0.060)		

Recommended Pad Layout



Dimension	SMB (DO-214AA)
A (Max.)	2.69
A (IVIAX.)	(0.106)
B (Min.)	2.10
	(0.083)
C (Min.)	1.27
C (Min.)	(0.050)

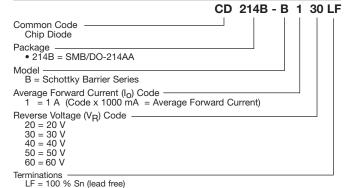
Physical Specifications

Case	Molded plastic
Polarity	Indicated by cathode band
Weight	0.003 ounces / 0.093 grams

Typical Part Marking

CD214B-B120 😕 1	20B
CD214B-B130 😝 1	30B
CD214B-B140 3 1	40B
CD214B-B150 B 1	
CD214B-B160 B 1	60B

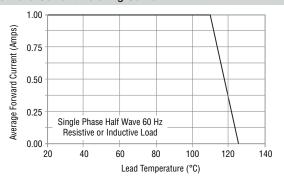
How To Order



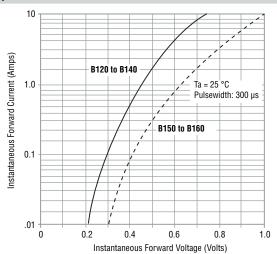
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Rating and Characteristic Curves

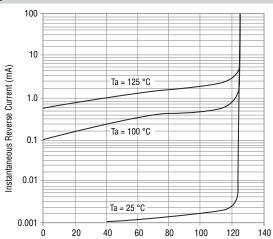
Forward Current Derating Curve



Typical Forward Characteristics



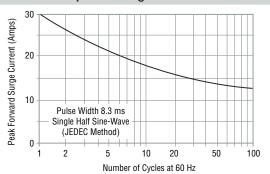
Typical Reverse Characteristics



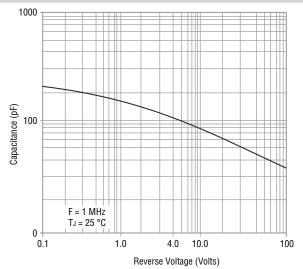
Percent of Rated Peak Reverse Voltage (%)

*RoHS Directive 2002/95/EC Jan 27 2003 including Annex Specifications are subject to change without notice. Customers should verify actual device performance in their specific applications.

Maximum Non-Repetitive Surge Current



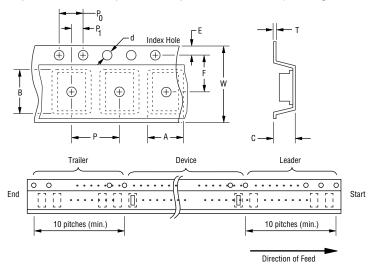
Typical Junction Capacitance

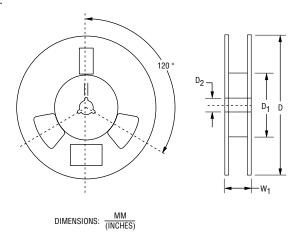


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Packaging Information

The product will be dispensed in Tape and Reel format (see diagram below).





Devices are packed in accordance with EIA standard RS-481-A and specifications shown here.

Item	Symbol	SMB (DO-214AA)
Carrier Width	А	$\frac{4.94 \pm 0.10}{(0.194 - 0.004)}$
Carrier Length	В	$\frac{5.57 \pm 0.10}{(0.219 - 0.004)}$
Carrier Depth	С	$\frac{2.36 \pm 0.10}{(0.093 - 0.004)}$
Sprocket Hole	d	$\frac{1.55 \pm 0.05}{(0.061 - 0.002)}$
Reel Outside Diameter	D	330 (12.992)
Reel Inner Diameter	D ₁	50.0 (1.969) MIN.
Feed Hole Diameter	D ₂	$\frac{13.0 \pm 0.20}{(0.512 - 0.008)}$
Sprocket Hole Position	Е	$\frac{1.75 \pm 0.10}{(0.069 - 0.004))}$
Punch Hole Position	F	$\frac{5.50 \pm 0.05}{(0.217 - 0.002)}$
Punch Hole Pitch	Р	$\frac{4.00 \pm 0.10}{(0.157 - 0.004)}$
Sprocket Hole Pitch	P ₀	$\frac{4.00 \pm 0.10}{(0.157 - 0.004)}$
Embossment Center	P ₁	$\frac{2.00 \pm 0.05}{(0.079 - 0.002)}$
Overall Tape Thickness	Т	$\frac{0.30 \pm 0.10}{(0.012 - 0.004)}$
Tape Width	W	$\frac{12.00 \pm 0.20}{(0.472 - 0.008)}$
Reel Width	W ₁	18.4 (0.724) MAX.
Quantity per Reel		3,000

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SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP
SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF
ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF
ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573
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